	Туре	L#	Hits	Search Text	DBs	Time Stamp
1	BRS	L1		(light adj emitting adj	USPAT; EPO; JPO; DERWEN T; IBM_TD B	2003/01/23 13:17
2	BRS	L2	75		USPAT; EPO; JPO; DERWEN T; IBM_TD B	2003/01/23 13:18

	Туре	L#	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	13		USPAT; EPO; JPO; DERWEN T; IBM_TD B	2003/01/23 12:31

	Туре	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	5434	display and (light adj emitting adj (device diode)) and semiconductor	USPAT; EPO; JPO; DERWEN T; IBM_TD B	2003/01/23 08:06
2	BRS	L2	405	1 and insulator and @ay<2002	USPAT; EPO; JPO; DERWEN T; IBM_TD B	2003/01/23 06:29
3	IS&R	L3	291	(313/500).CCLS.	USPAT; EPO; JPO; DERWEN T; IBM_TD B	07:24
4	BRS	L46	1243	:	USPAT; EPO; JPO; DERWEN T; IBM_TD B	2003/01/23 08:37
5	BRS	L47	1243	46 and display	USPAT; EPO; JPO; DERWEN T; IBM_TD B	2003/01/23 08:35
6	BRS	L48	64103		USPAT; EPO; JPO; DERWEN T; IBM_TD B	09:03

	Туре	L #	Hits	Search Text	DBs	Time Stamp
7	BRS	L49	12	48 and 148/33.ccls.	USPAT; EPO; JPO; DERWEN T; IBM_TD B	2003/01/23 08:40
8	BRS	L50	215	48 and 117/\$.ccls.	USPAT; EPO; JPO; DERWEN T; IBM_TD B	2003/01/23 08:48
9	BRS	L51	15	48 and 29/25.01.ccls.	USPAT; EPO; JPO; DERWEN T; IBM_TD B	2003/01/23 08:49
10	BRS	L52	2303	48 and 438/\$.ccls.	USPAT; EPO; JPO; DERWEN T; IBM_TD B	2003/01/23 08:51
11	BRS	L53	6143	(laser (light adj emitting adj diode)) adj array	USPAT; EPO; JPO; DERWEN T; IBM_TD B	2003/01/23 09:04
12	BRS	L54	6001	53 and @ay<2002	USPAT; EPO; JPO; DERWEN T; IBM_TD B	2003/01/23 09:06

	Туре	L #	Hits	Search Text	DBs	Time Stamp
13	BRS	L55	54	54 and 372/44.ccls.	USPAT; EPO; JPO; DERWEN T; IBM_TD B	2003/01/23 09:11
14	BRS	L56	109	54 and 257/88.ccls.	USPAT; EPO; JPO; DERWEN T; IBM_TD B	2003/01/23 09:11
15	IS&R	L59	2	("6190935").PN.	USPAT; EPO; JPO; DERWEN T; IBM_TD B	2003/01/23 09:24

	Туре	L #	Hits	Search Text	DBs	Time Stamp
16	BRS	L60	124	(light adj emitting adj (device diode)) and	USPAT; EPO; JPO; DERWEN T; IBM_TD B	2003/01/23 09:42